### NE5534, NE5534A, SA5534. SA5534A LOW-NOISE OPERATIONAL AMPLIFIERS

SLOS070C - JULY 1979 - REVISED SEPTEMBER 2004

- Equivalent Input Noise Voltage . . . 3.5 nV/√Hz Typ
- Unity-Gain Bandwidth . . . 10 MHz Typ
- Common-Mode Rejection Ratio . . . 100 dB Typ
- High DC Voltage Gain . . . 100 V/mV Typ
- **Peak-to-Peak Output Voltage Swing** 32 V Typ With  $V_{CC\pm}$  = ±18 V and  $R_L$  = 600  $\Omega$
- High Slew Rate . . . 13 V/us Typ
- Wide Supply-Voltage Range ±3 V to ±20 V
- **Low Harmonic Distortion**
- Offset Nulling Capability
- **External Compensation Capability**

#### NE5534, SA5534 . . . D (SOIC), P (PDIP), OR PS (SOP) PACKAGE NE5534A, SA5534A . . . D (SOIC) OR P (PDIP) PACKAGE (TOP VIEW) 8 COMP/BAL BALANCE [ $V_{CC+}$ IN- [ 7 6 ∏OUT IN+ [] 3 5 ПСОМР

### description/ordering information

The NE5534, NE5534A, SA5534, and SA5534A are high-performance operational amplifiers combining excellent dc and ac characteristics. Some of the features include very low noise, high output-drive capability, high unity-gain and maximum-output-swing bandwidths, low distortion, and high slew rate.

These operational amplifiers are compensated internally for a gain equal to or greater than three. Optimization of the frequency response for various applications can be obtained by use of an external compensation capacitor between COMP and COMP/BAL. The devices feature input-protection diodes, output short-circuit protection, and offset-voltage nulling capability with use of the BALANCE and COMP/BAL pins (see the application circuit diagram).

For the NE5534A and SA5534A, a maximum limit is specified for the equivalent input noise voltage.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



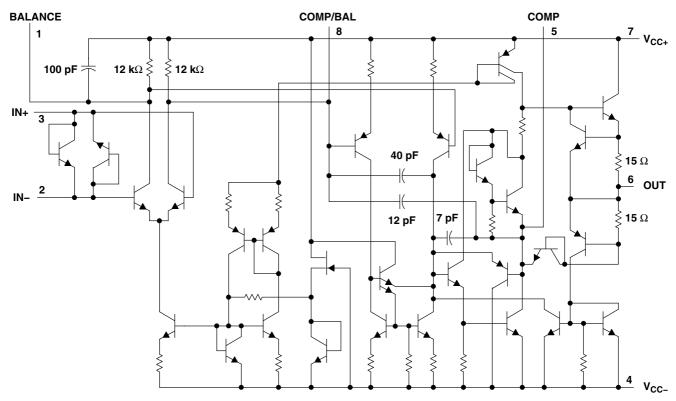
### description/ordering information (continued)

#### **ORDERING INFORMATION**

T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	PACKA	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		DDID (D)	Tube of 50	NE5534P	NE5534P
		PDIP (P)	Tube of 50	NE5534AP	NE5534AP
			Tube of 75	NE5534D	NECCO4
0°C to 70°C	4 mV	COIC (D)	Reel of 2500	NE5534DR	NE5534
		SOIC (D)	Tube of 75	NE5534AD	55044
			Reel of 2500	NE5534ADR	5534A
		SOP (PS)	Reel of 2000	NE5534PSR	N5534
		DDID (D)	Tube of 50	SA5534P	SA5534P
		PDIP (P)	Tube of 50	SA5534AP	SA5534AP
			Tube of 75	SA5534D	
4000 1 0500	,	SOIC (D)	Reel of 2500	SA5534DR	SA5534
–40°C to 85°C	4 mV	SOIC (D)	Tube of 75	SA5534AD	CAFFOAA
			Reel of 2500	SA5534ADR	SA5534A
		COD (DC)	Tube of 80	SA553APS	CAFEOA
		SOP (PS)	Reel of 2000	SA553APSR	SA5534

<sup>&</sup>lt;sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### schematic

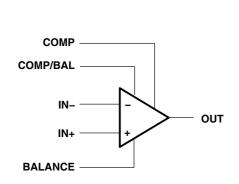


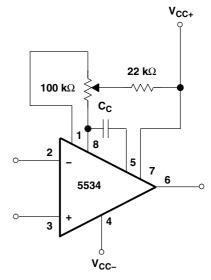
All component values shown are nominal.



### symbol

### application circuit





Frequency Compensation and Offset-Voltage Nulling Circuit

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage: V <sub>CC+</sub> (see Note 1)	22 V
V <sub>CC</sub> - (see Note 1)	
Input voltage either input (see Notes 1 and 2)	V <sub>CC+</sub>
Input current (see Note 3)	±10 mA
Duration of output short circuit (see Note 4)	Unlimited
Package thermal impedance, $\theta_{JA}$ (see Notes 5 and 6):	D package 97°C/W
	P package 85°C/W
	PS package 95°C/W
Operating virtual junction temperature, T <sub>J</sub>	150°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V<sub>CC+</sub> and V<sub>CC-</sub>.
  - 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage.
  - 3. Excessive current will flow if a differential input voltage in excess of approximately 0.6 V is applied between the inputs, unless some limiting resistance is used.
  - 4. The output may be shorted to ground or to either power supply. Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.
  - 5. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
  - 6. The package thermal impedance is calculated in accordance with JESD 51-7.

### recommended operating conditions

			MIN	MAX	UNIT
V <sub>CC+</sub>	Supply voltage		5	15	V
V <sub>CC</sub> -	Supply voltage		-5	-15	V
_		NE5534, NE5534A	0	70	°C
T <sub>A</sub>	Operating free-air temperature range	SA5534, SA5534A	-40	85	C



### NE5534, NE5534A, SA5534. SA5534A LOW-NOISE OPERATIONAL AMPLIFIERS

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## electrical characteristics, $V_{CC}\pm$ = $\pm15$ V, $T_{A}$ = $25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDI	TIONS†	MIN	TYP	MAX	UNIT
,,	lament offerst violations	$V_{O} = 0,$	T <sub>A</sub> = 25°C		0.5	4	
$V_{IO}$	Input offset voltage	$R_S = 50 \Omega$	T <sub>A</sub> = Full range			5	mV
	land offer at a constant	V 0	T <sub>A</sub> = 25°C		20	300	4
I <sub>IO</sub>	Input offset current	$V_O = 0$	$T_A = Full range$			400	nA
	Innut bice current	V 0	T <sub>A</sub> = 25°C		500	1500	nA
I <sub>IB</sub>	Input bias current	$V_O = 0$	$T_A = Full range$			2000	ΠA
V <sub>ICR</sub>	Common-mode input voltage range			±12	±13		٧
,	Marian and the most subset with an arrive	D > 000 O	$V_{CC\pm} = \pm 15 \text{ V}$	24	26		٧
V <sub>O(PP)</sub>	Maximum peak-to-peak output voltage swing	$R_L \ge 600 \Omega$	$V_{CC\pm} = \pm 18 \text{ V}$	30	32		٧
	Lavas aignal differential vallege appelification	$V_0 = \pm 10 \text{ V},$	T <sub>A</sub> = 25°C	25	100		V/mV
$A_{VD}$	Large-signal differential voltage amplification	$R_L \ge 600 \Omega$	$T_A = Full range$	15			V/IIIV
	Consultational differential valleges are differential	4 40 141-	C <sub>C</sub> = 0		6		V/mV
A <sub>vd</sub>	Small-signal differential voltage amplification	f = 10 kHz	$C_C = 22 pF$		2.2		V/IIIV
		V 140 V	C <sub>C</sub> = 0		200		
B <sub>OM</sub>	Maximum-output-swing bandwidth	$V_O = \pm 10 \text{ V}$	$C_C = 22 pF$	95			kHz
БОМ	Maximum output swing bandwidth	$V_{CC\pm} = \pm 18 \text{ V},$ $R_L \ge 600 \Omega,$	$V_O = \pm 14 \text{ V},$ $C_C = 22 \text{ pF}$	70			
B <sub>1</sub>	Unity-gain bandwidth	$C_C = 22 \text{ pF},$	C <sub>L</sub> = 100 pF		10		MHz
r <sub>i</sub>	Input resistance			30	100		kΩ
z <sub>o</sub>	Output impedance	$A_{VD} = 30 \text{ dB},$ $C_{C} = 22 \text{ pF},$	$R_L \ge 600 \Omega$ , $f = 10 \text{ kHz}$		0.3		Ω
CMRR	Common-mode rejection ratio	$V_O = 0$ , $R_S = 50 \Omega$	$V_{IC} = V_{ICR}min^{-1}$	70	100		dB
k <sub>SVR</sub>	Supply-voltage rejection ratio ( $\Delta V_{CC}/\Delta V_{IO}$ )	$V_{CC+} = \pm 9 \text{ V to } \pm 15 \text{ V},$ $V_{O} = 0$	$R_S = 50 \Omega$ ,	80	100		dB
Ios	Output short-circuit current				38		mA
Icc	Supply current	V <sub>O</sub> = 0, No load	T <sub>A</sub> = 25°C	_	4	8	mA

<sup>†</sup> All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. For NE5534 and NE5534A, full range is 0°C to 70°C. For SA5534 and SA5534A, full range is –40°C to 85°C.

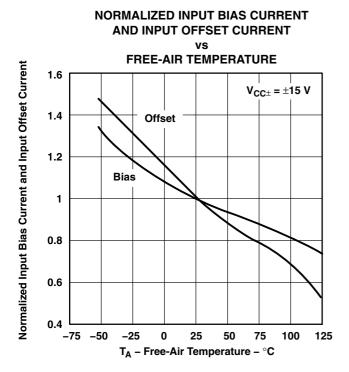
### NE5534, NE5534A, SA5534. SA5534A LOW-NOISE OPERATIONAL AMPLIFIERS

SLOS070C - JULY 1979 - REVISED SEPTEMBER 2004

### operating characteristics, $V_{CC}\,\pm$ = $\pm15$ V, $T_{A}$ = $25^{\circ}C$

	PARAMETER	TEST (	CONDITIONS	NE5534, SA5534	NE5534	4A, SA5	534A	UNIT	
				TYP	MIN TYP MAX		MAX		
CD	Classificate	C <sub>C</sub> = 0		13		13		Mora	
SR	Slew rate	C <sub>C</sub> = 22 pF		6		6		V/μs	
	Rise time		$A_{VD} = 1$ , $C_C = 22 pF$	20		20		ns	
	Overshoot factor	$R_L = 600 \Omega,$ $C_L = 100 pF$	OC = 22 br	20		20		%	
t <sub>r</sub>	Rise time	$V_1 = 50 \text{ mV},$	$A_{VD} = 1$ , $C_C = 47 \text{ pF}$	50	50	50		ns	
	Overshoot factor	$R_L = 600 \Omega,$ $C_L = 500 pF$	OC = 47 PF	35		35		%	
v	Cavinglant input paige veltage	f = 30 Hz		7		5.5	7	\/\	
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz		4		3.5	4.5	nV/√Hz	
	Fundament in the control of the cont	f = 30 Hz		2.5		1.5		- A / /III	
In	Equivalent input noise current	f = 1 kHz		0.6		0.4		pA/√ <del>Hz</del>	
F	Average noise figure	$R_S = 5 k\Omega$	f = 10 Hz to 20 kHz			0.9		dB	

### TYPICAL CHARACTERISTICS<sup>†</sup>



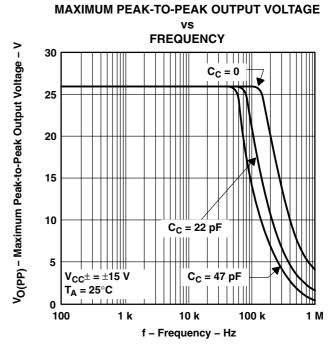
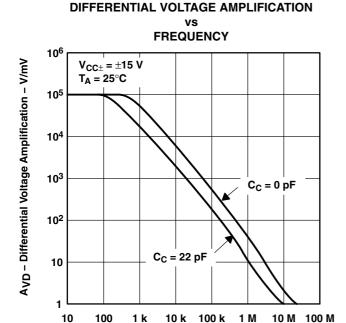


Figure 1

**LARGE-SIGNAL** 

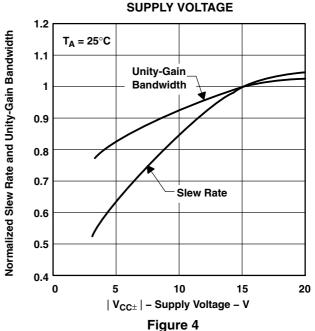
Figure 2



f - Frequency - Hz

Figure 3

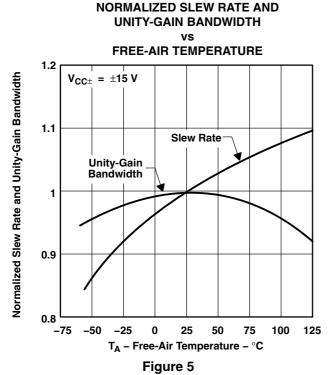
# **NORMALIZED SLEW RATE AND UNITY-GAIN BANDWIDTH**

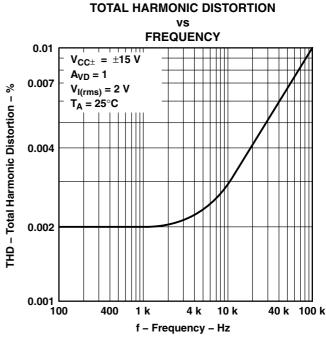


<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



#### TYPICAL CHARACTERISTICS<sup>†</sup>





# **EQUIVALENT INPUT NOISE VOLTAGE FREQUENCY**

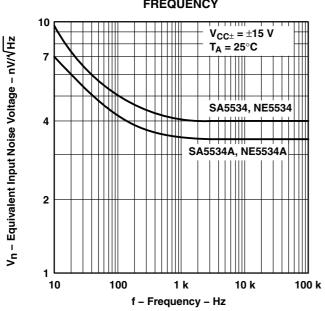
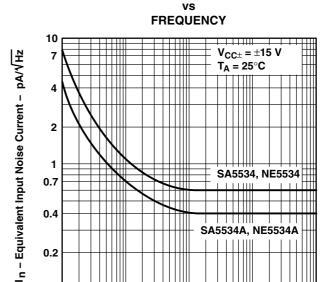


Figure 7



SA5534A, NE5534A

Figure 6

**EQUIVALENT INPUT NOISE CURRENT** 

10 100 1 k 10 k f - Frequency - Hz

Figure 8

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



0.4

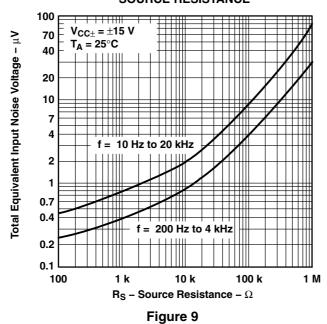
0.2

0.1

100 k

### TYPICAL CHARACTERISTICS

### TOTAL EQUIVALENT INPUT NOISE VOLTAGE vs SOURCE RESISTANCE







10-Jun-2014

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
NE5534AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	5534A	Samples
NE5534ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	5534A	Samples
NE5534ADRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	5534A	Samples
NE5534ADRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	5534A	Samples
NE5534AJG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		
NE5534AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5534AP	Samples
NE5534APE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5534AP	Samples
NE5534D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	NE5534	Samples
NE5534DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	NE5534	Samples
NE5534DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	NE5534	Samples
NE5534DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	NE5534	Samples
NE5534IP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI	0 to 70		
NE5534P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5534P	Samples
NE5534PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	NE5534P	Sample
SA5534AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SA5534A	Samples
SA5534ADE4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Sample
SA5534ADG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SA5534A	Samples
SA5534ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SA5534A	Samples





www.ti.com 10-Jun-2014

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SA5534ADRE4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Samples
SA5534ADRG4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Samples
SA5534AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SA5534AP	Samples
SA5534APE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SA5534AP	Samples
SA5534D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SA5534	Samples
SA5534DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SA5534	Samples
SA5534DG4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Samples
SA5534DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SA5534	Samples
SA5534DRE4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Samples
SA5534DRG4	ACTIVE	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		Samples
SA5534P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SA5534P	Samples
SA5534PE4	ACTIVE	PDIP	Р	8		TBD	Call TI	Call TI	-40 to 85		Samples
SA5534PSR	ACTIVE	so	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SA5534	Samples
SA5534PSRE4	ACTIVE	SO	PS	8		TBD	Call TI	Call TI	-40 to 85		Samples
SA5534PSRG4	ACTIVE	SO	PS	8		TBD	Call TI	Call TI	-40 to 85		Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



### **PACKAGE OPTION ADDENDUM**

10-Jun-2014

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

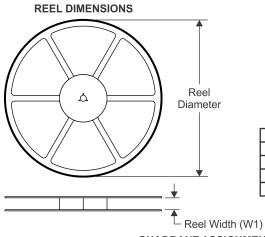
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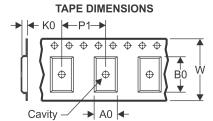
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### PACKAGE MATERIALS INFORMATION

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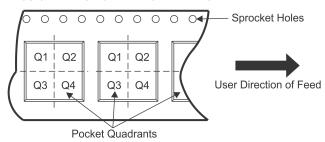
### TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

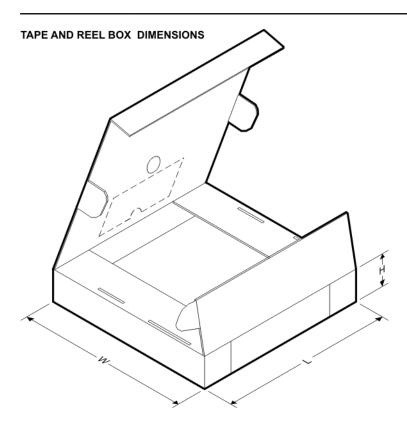
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
NE5534ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE5534DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SA5534ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SA5534DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SA5534PSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1

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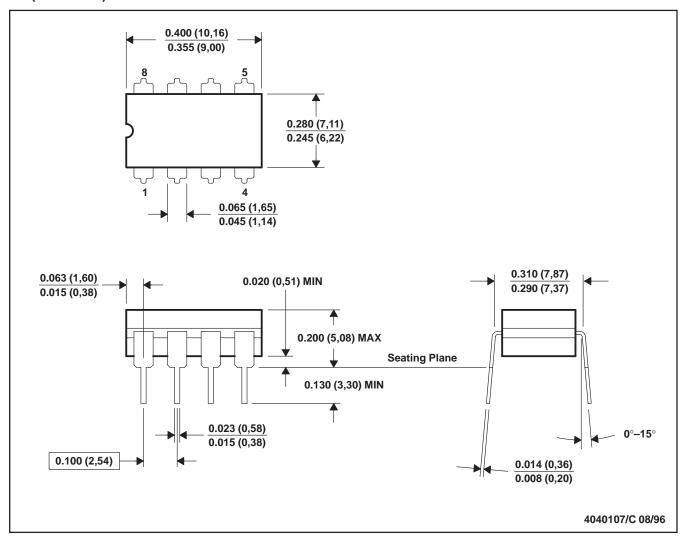


\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
NE5534ADR	SOIC	D	8	2500	340.5	338.1	20.6
NE5534DR	SOIC	D	8	2500	340.5	338.1	20.6
SA5534ADR	SOIC	D	8	2500	340.5	338.1	20.6
SA5534DR	SOIC	D	8	2500	340.5	338.1	20.6
SA5534PSR	SO	PS	8	2000	367.0	367.0	38.0

### JG (R-GDIP-T8)

#### **CERAMIC DUAL-IN-LINE**

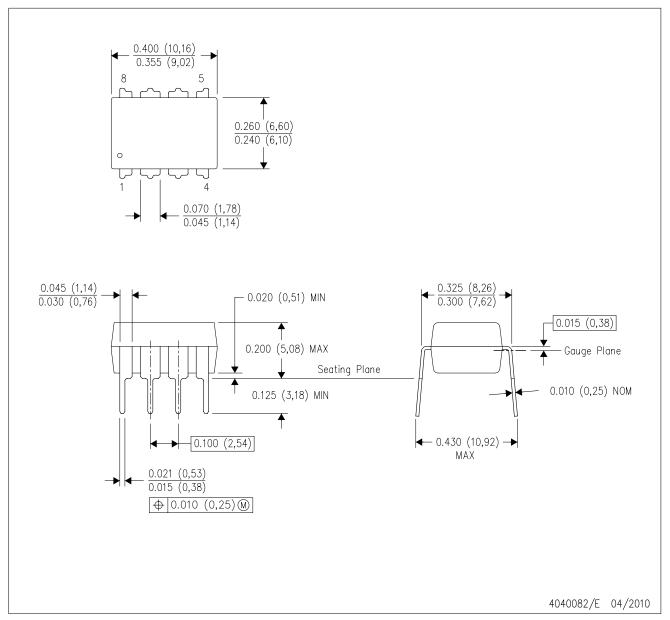


NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

### P (R-PDIP-T8)

### PLASTIC DUAL-IN-LINE PACKAGE



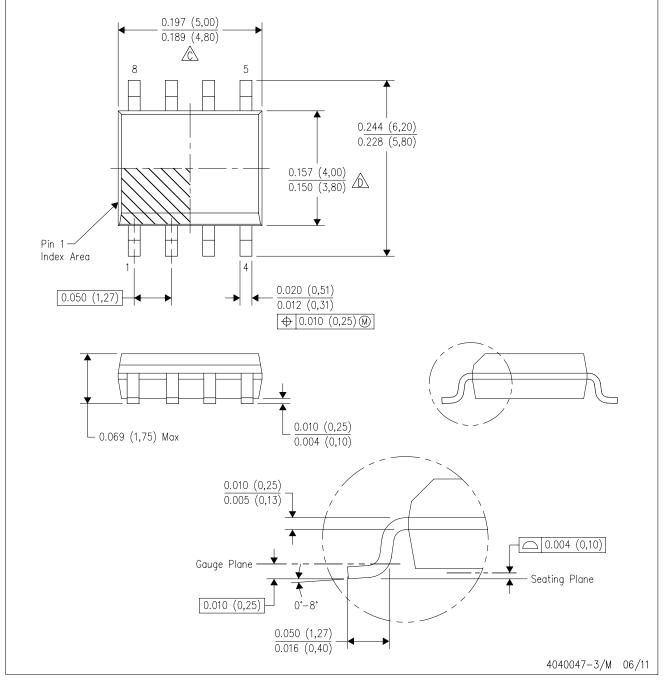
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



### D (R-PDSO-G8)

### PLASTIC SMALL OUTLINE



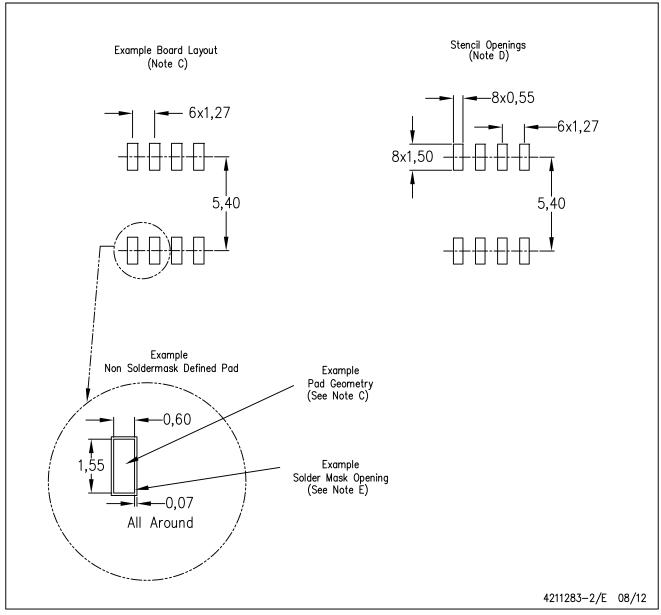
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



# D (R-PDSO-G8)

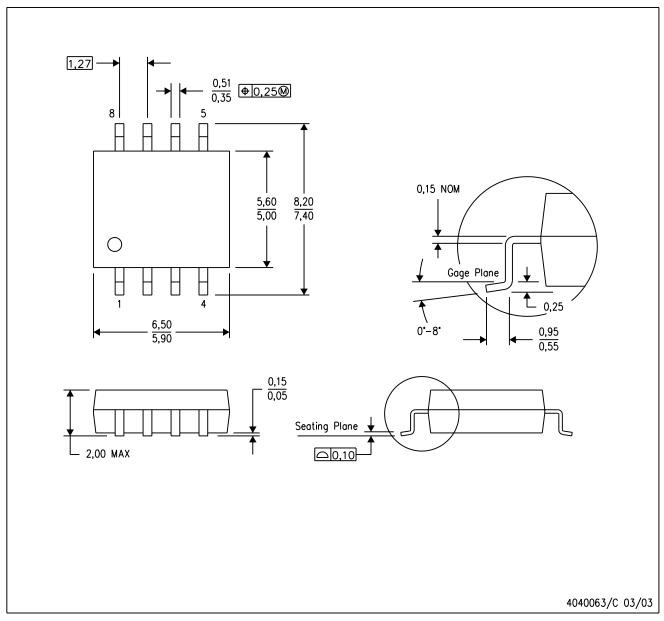
### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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